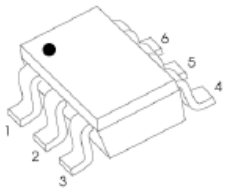
MMDT3904

DUAL TRANSISTOR (NPN+NPN)

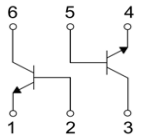
SOT-363



FEATURES

- Epitaxial planar die construction
- Ideal for low power amplification and switching

MARKING: K6N



MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

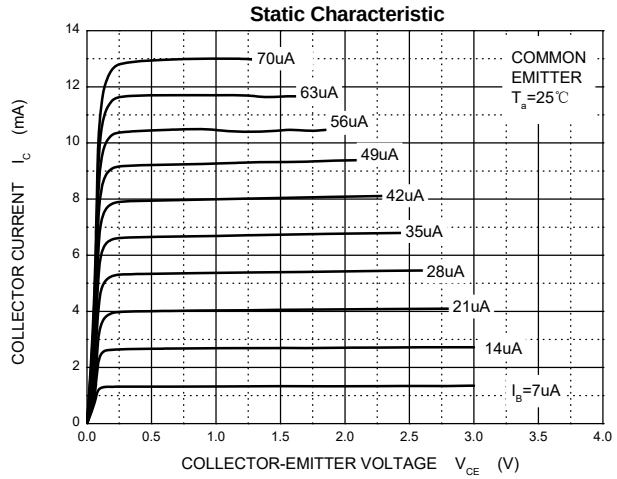
Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	0.2	A
P_C	Collector Power Dissipation	0.2	W
T_J	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55-150	℃

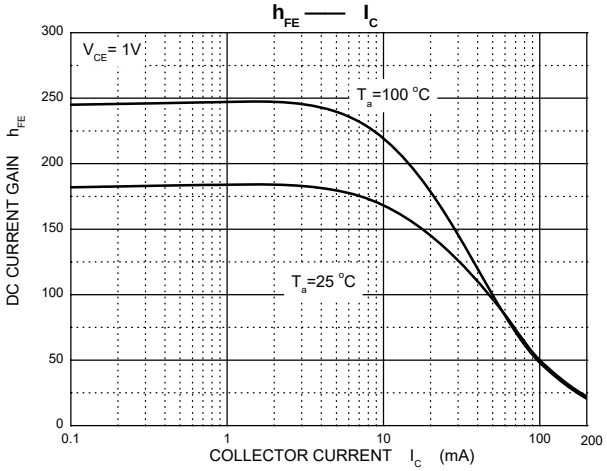
ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)

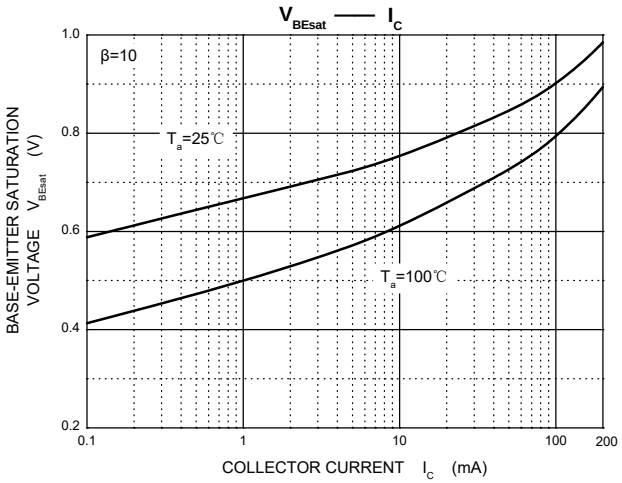
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=10μA,I_E=0	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=1mA,I_B=0	40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=10μA,I_C=0	5			V
Collector cut-off current	I_{CBO}	V_{CB}=30V,I_E=0			0.05	μA
Emitter cut-off current	I_{EBO}	V_{EB}=5V,I_C=0			0.05	μA
Collector cut-off current	I_{CEX}	V_{CE}=30V,$V_{BE(off)}$=3V			0.05	μA
DC current gain	$h_{FE(1)}$	V_{CE}=1V,I_C=0.1mA	40			
	$h_{FE(2)}$	V_{CE}=1V,I_C=1mA	70			
	$h_{FE(3)}$	V_{CE}=1V,I_C=10mA	100		300	
	$h_{FE(4)}$	V_{CE}=1V,I_C=50mA	60			
	$h_{FE(5)}$	V_{CE}=1V,I_C=100mA	30			
Collector-emitter saturation voltage	$V_{CE(sat)1}$	I_C=10mA,I_B=1mA			0.2	V
	$V_{CE(sat)2}$	I_C=50mA,I_B=5mA			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)1}$	I_C=10mA,I_B=1mA	0.65		0.85	V
	$V_{BE(sat)2}$	I_C=50mA,I_B=5mA			0.95	V
Transition frequency	f_T	V_{CE}=20V,I_C=10mA,f=100MHz	300			MHz
Collector output capacitance	C_{ob}	V_{CB}=5V,I_E=0,f=1MHz			4	pF
Noise figure	NF	V_{CE}=5V,I_c=0.1mA,f=1kHz,R_S=1KΩ			5	dB
Delay time	t_d	V_{CC}=3V, $V_{BE(off)}$=-0.5V			35	nS
Rise time	t_r	I_C=10mA , I_{B1}=-I_{B2}= 1mA			35	nS
Storage time	t_s	V_{CC}=3V, I_C=10mA			200	nS
Fall time	t_f	I_{B1}=-I_{B2}=1mA			50	nS

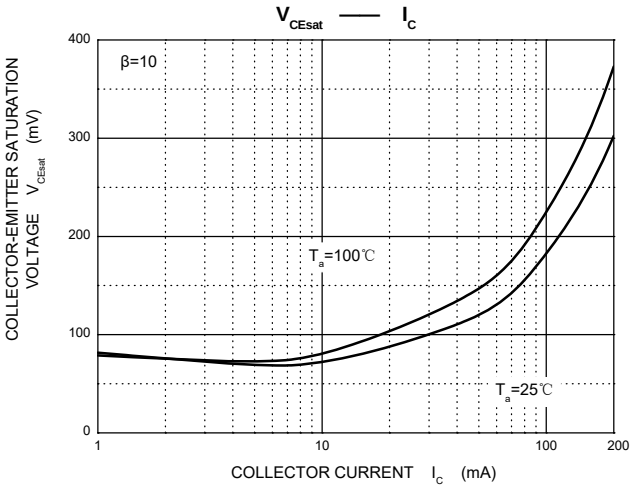
WPMtek

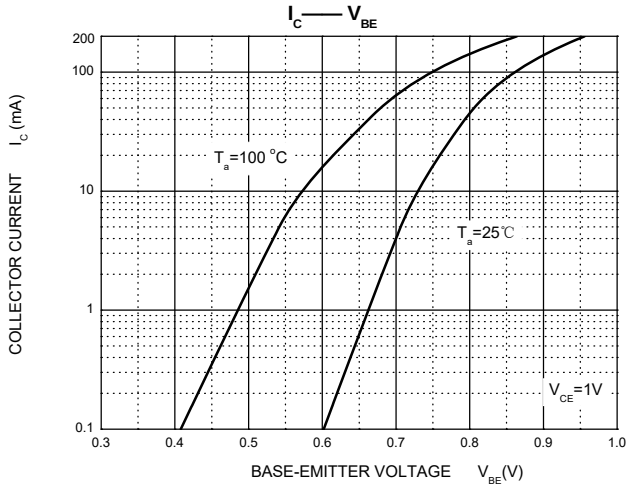
Typical Characteristics

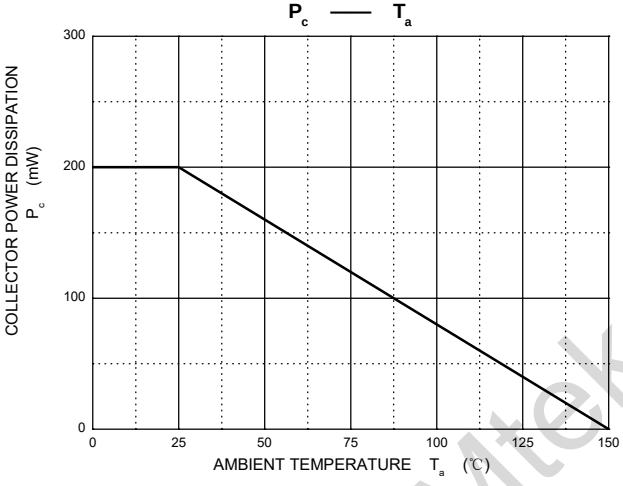






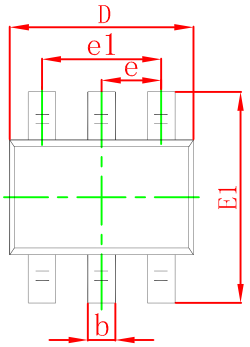


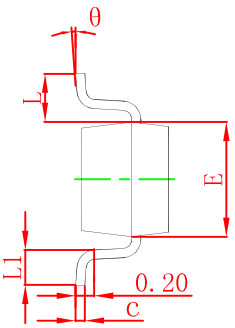


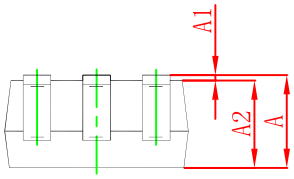


WPMtek

SOT-363 Package Outline Dimensions

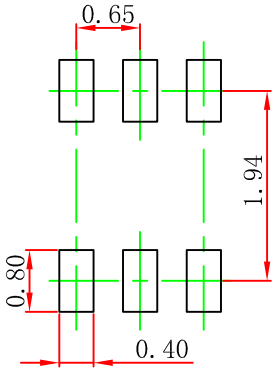






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-363 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

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